

# MJD360T4-A MJD361T4-A

### Low voltage complementary power transistors

#### Preliminary data

### Features

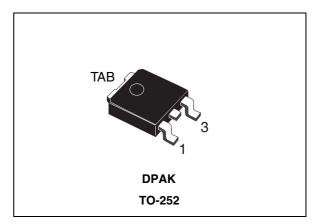
- Those devices are qualified for automotive application
- Low collector emitter saturation voltage
- Surface-mounting TO-252 power package in tape and reel

### Applications

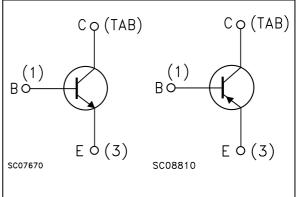
 General purpose switching and amplifier transistor

### Description

The devices are manufactured in planar technology with "base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.



#### Figure 1. Internal schematic diagrams



#### Table 1. Device summary

Order code	Marking	Polarity	Package	Packaging
MJD360T4-A	MJD360	NPN	DPAK	Tape and reel
MJD361T4-A	MJD361	PNP	DIAN	Tape and teel

August 2009

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This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

## 1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage $(I_E = 0)$	60	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	60	V
$V_{\text{EBO}}$	Emitter-base voltage ( $I_{\rm C} = 0$ )	5	V
۱ <sub>C</sub>	Collector current	3	А
I <sub>CM</sub>	Collector peak current	5	А
I <sub>B</sub>	Base current	1	А
P <sub>TOT</sub>	Total dissipation at $T_c = 25 \ ^{\circ}C$	15	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative.

### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max.	8.3	°C/W

## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CE</sub> = 60 V				20	μA
I <sub>EBO</sub>	Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = 4 V				100	μA
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA		60			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 1 mA		60			v
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage $(I_C = 0)$	I <sub>C</sub> = 100 μA		5			۷
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = 200 \text{ mA}$ $I_C = 1 \text{ A}$ $I_C = 3 \text{ A}$	I <sub>B</sub> = 50 mA			0.1 0.3 0.9	<pre>&gt; &gt; &gt;</pre>
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 200 \text{ mA}$ $I_C = 1 \text{ A}$ $I_C = 3 \text{ A}$		90 60 30	130 100 60		

Table 4. Elect	rical chai	racteristics
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1. Pulse test: pulse duration  $\leq$ 300 µs, duty cycle  $\leq$  %.

Note: For PNP types voltage and current values are negative.



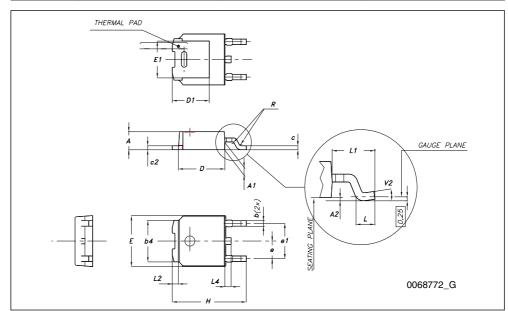
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



DIM.		mm.	
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
с	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °

#### TO-252 (DPAK) mechanical data



## 4 Revision history

### Table 5.Document revision history

Date	Revision	Changes
14-Aug-2009	1	Initial release.



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